

Issues – image formation & acquisition

1. **Amplitude and phase contrast in cryoEM**
 2. **Recording the image, detectors, MTF and DQE**
-

We don't detect all the electrons (half or less than half)

Those electrons which lose energy (inelastically scattered) are often badly focussed and contribute only noise

We don't extract the optimum phase contrast signal.

- **Better detectors with higher DQE and MTF**
- **C_c correctors to focus electrons with a wider ΔE**
- **Quarter-wave plates to optimize phase contrast**

**CONTRAST TRANSFER FOR FROZEN-HYDRATED SPECIMENS:
DETERMINATION FROM PAIRS OF DEFOCUSED IMAGES**

Chikashi TOYOSHIMA *

Department of Cell Biology, Stanford University School of Medicine, Stanford, California 94305, USA

and

Nigel UNWIN

Medical Research Council Laboratory of Molecular Biology, Hills Road, Cambridge CB2 2QH, UK

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Electron imaging of frozen-hydrated biological molecules allows density maps to be obtained directly, without the need for fixatives or stains. The appearance of such maps may, however, be strongly influenced by the contrast transfer properties, which have not previously been evaluated by quantitative experiments. Here we determine the contribution due to amplitude contrast in a typical ($\sim 300 \text{ \AA}$ thick) frozen specimen, consisting of arrays of acetylcholine receptor, by comparing pairs of images recorded with different defocuses. We find that this specimen is imaged as a "weak-phase-weak-amplitude" object and that the contribution due to amplitude contrast is 7%. (at 120kV)

See also Toyoshima et al, Ultramicroscopy (1993) 48, 165-176

120kV – 5.8%

200kV – 4.8%

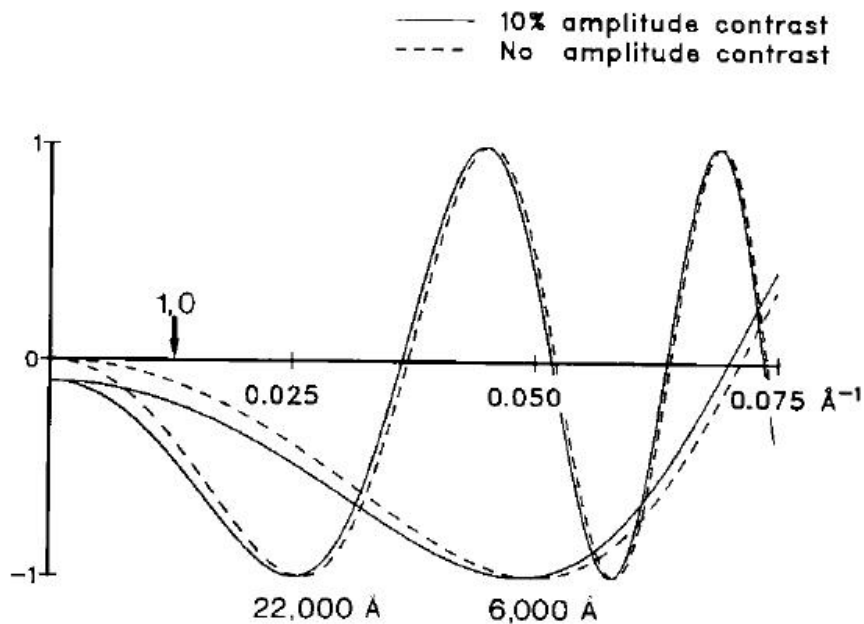


Fig. 1. Theoretical CTFs, $C(v)$, for 6000 Å and 22000 Å underfocus, assuming pure phase contrast (broken lines) or 10% amplitude contrast (solid lines). By comparing the ratio of the CTFs at a given spatial frequency, it is possible to estimate the proportion of amplitude contrast. For example, at a spatial

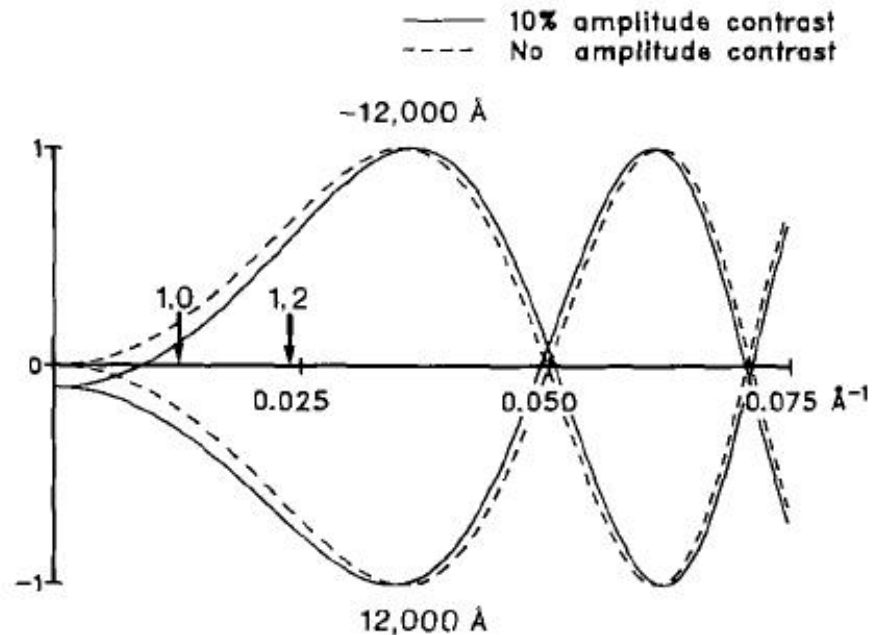


Fig. 6. Theoretical CTFs for the defocus conditions realized in fig. 7 (± 12000 Å defocus). Solid and broken lines correspond to 10% and 0% amplitude contrast, respectively. The spatial frequencies corresponding to the (1,0) and (1,2) reflections are indicated; at these low spatial frequencies the phase and amplitude contrast contributions are of opposite sign and therefore tend to cancel when the image is overfocused, but are of the same sign and reinforce one another when the image is under-focused. Thus at low spatial frequencies comparison of under-focused-overfocused pairs of images provides a sensitive means of measuring the amplitude contrast contribution.

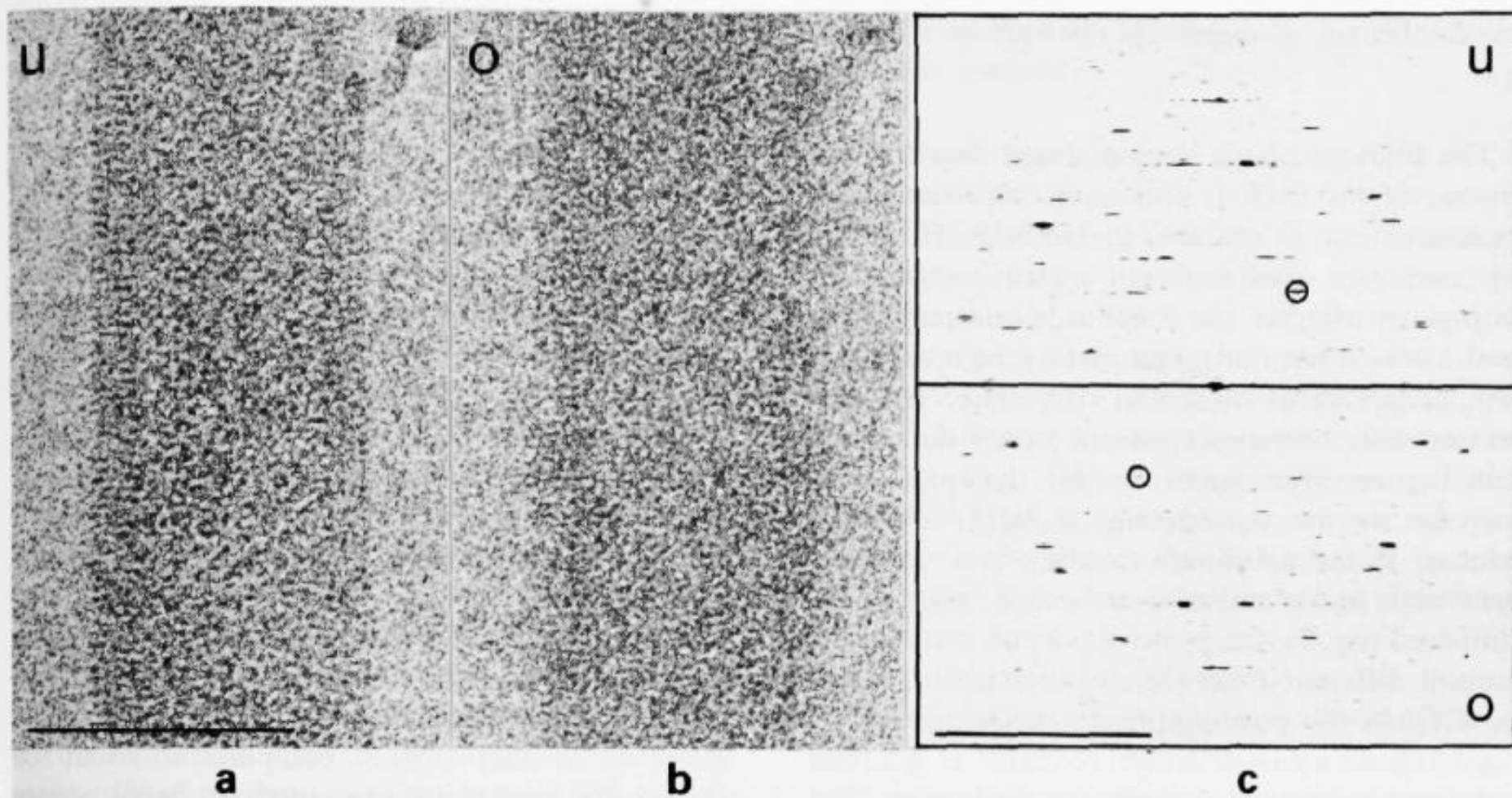


Fig. 7. Images of an ice-embedded tube recorded at 12000 \AA underfocus (a) and 12000 \AA overfocus (b), and a composite of their diffraction patterns (c). The (1,0) reflections from one side of the tube are marked. U and O denote under- and overfocus, respectively. Note that lower resolution reflections appear much weaker in the diffraction pattern from the overfocused image (lower half, (c)) than in the underfocused one (upper half, (c)), due to a partial cancellation of phase and amplitude contrast. The overfocused image was recorded after the underfocused image so that the effect cannot be due to radiation damage. Bars correspond to $0.1 \mu\text{m}$ (a) and $1/50 \text{ \AA}^{-1}$ (b).

Understanding images of unstained biological molecules

100 keV electron scattering factors (IAM)

	$ f $ per atom	η
H	0.63	0.008
C	2.90	0.037
N	2.57	0.045
O	2.34	0.052
S	6.08	0.08
U	22	0.22

Some problems in understanding images of unstained biological molecules

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Embedding in ice

Ratio of amplitude to phase contrast

$$\begin{aligned}\eta_{(p-w)} &= (\mathbf{f}_p \eta_p - \mathbf{f}_w \eta_w) / (\mathbf{f}_p - \mathbf{f}_w) \\ &= \eta_p + (\mathbf{f}_w / (\mathbf{f}_p - \mathbf{f}_w)) \cdot (\eta_p - \eta_w)\end{aligned}$$

M.W.		 f /mol or /res	moles /Å³	 f /Å³	η	estimated “fudge” from bonding		density used (g/cc)
18	H₂O (ice)	3.6	0.033	0.12	0.036	0.13	0.03	1.0
108.5	protein (lo dose)	25.7	0.008	0.198	0.035	0.18	0.04	1.4
	protein (hi dose)	~13	~0.008	~0.10	~0.04	~0.10	~0.04	0.7
376	UA (lo dose)	48.7	0.0048	0.23	0.12	0.22	0.14	3.0
~300	UA (hi dose)	~35	~0.006	~0.21	~0.17	~0.21	~0.17	3.0
	UA - prot (lo dose)	-	-	0.032	0.64	0.05	0.48	-
	UA - prot (hi dose)	-	-	~0.11	~0.27	~0.11	~0.27	-
	prot - ice	-	-	0.08	0.035	0.05	0.066	-

Note: for high dose images of negatively stained specimens, a 50% mass loss of organic matter has been assumed compared with low does images.

Detectors for Electron Microscopy

Film (SO-163)

Phosphor/Fibre Optics/cooled CCD

Phosphor/Lens/cooled CCD

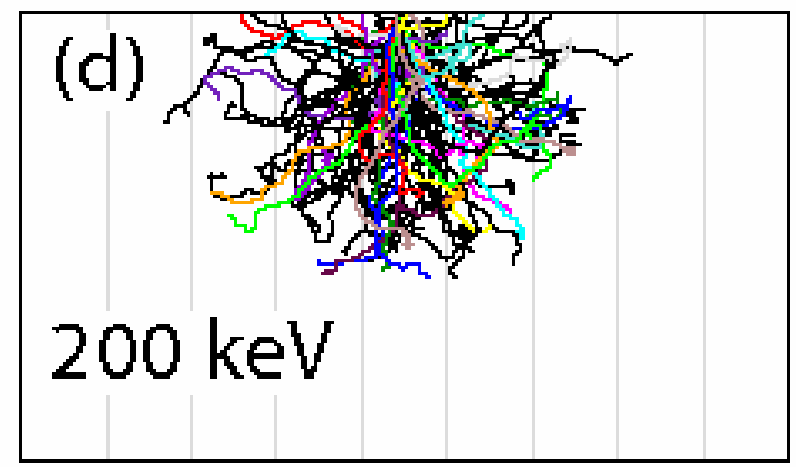
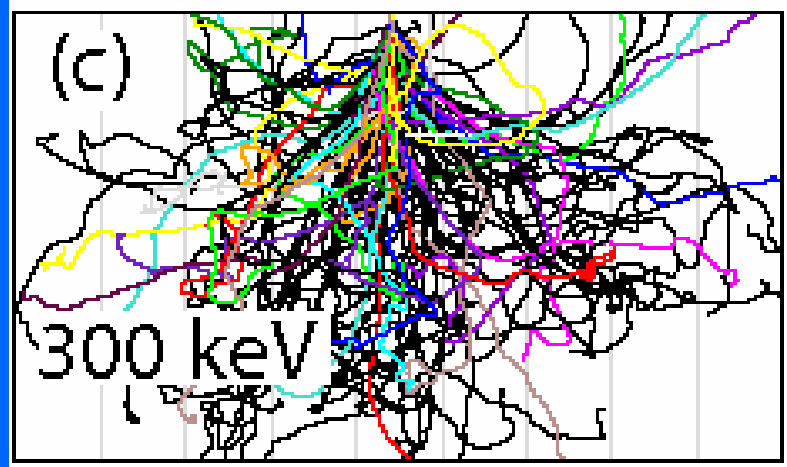
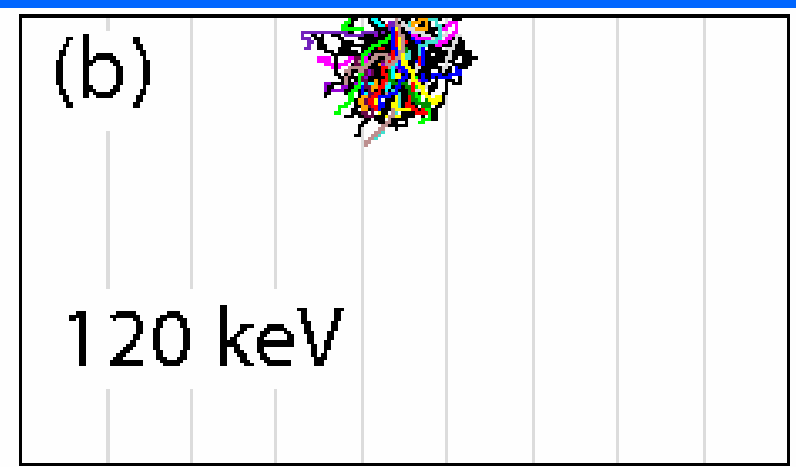
Hybrid Pixel Detectors (Medipix)

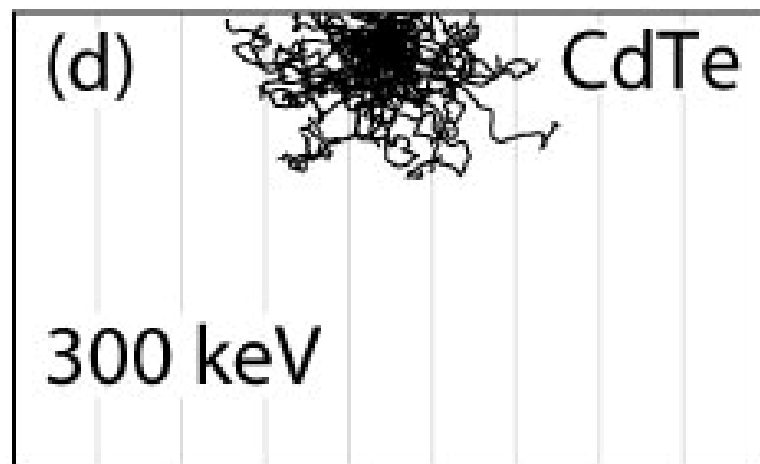
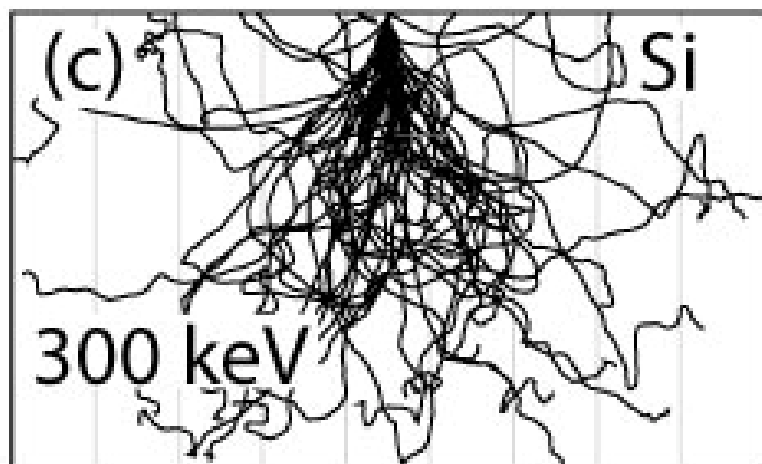
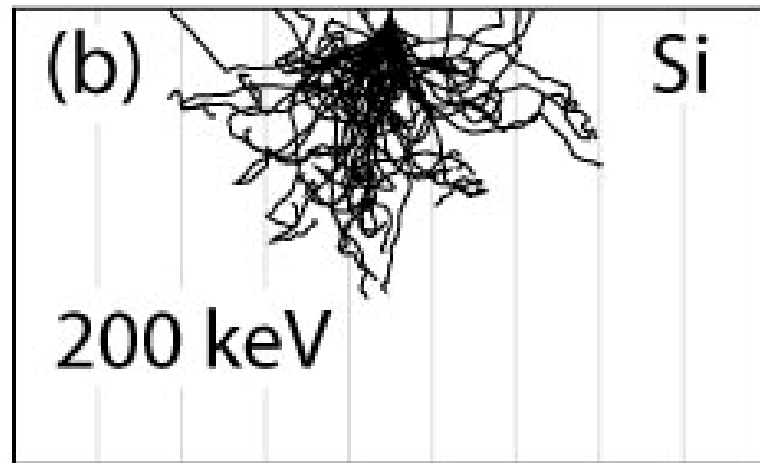
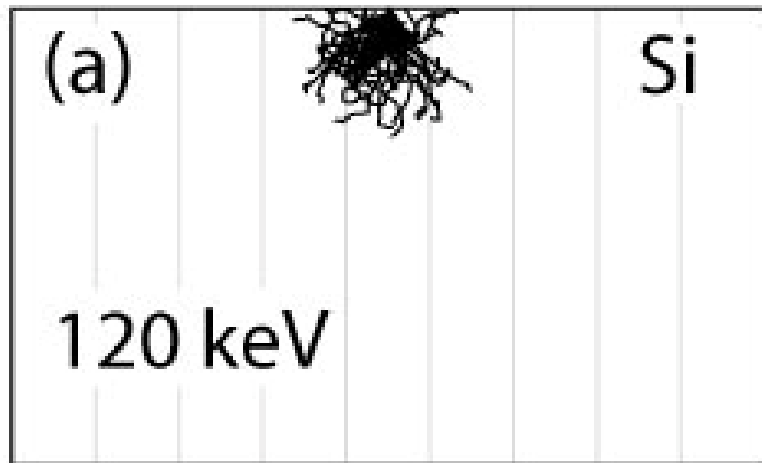
Monolithic Active Pixel Sensors (MAPS/CMOS)

Monte Carlo simulation of electron trajectories in silicon

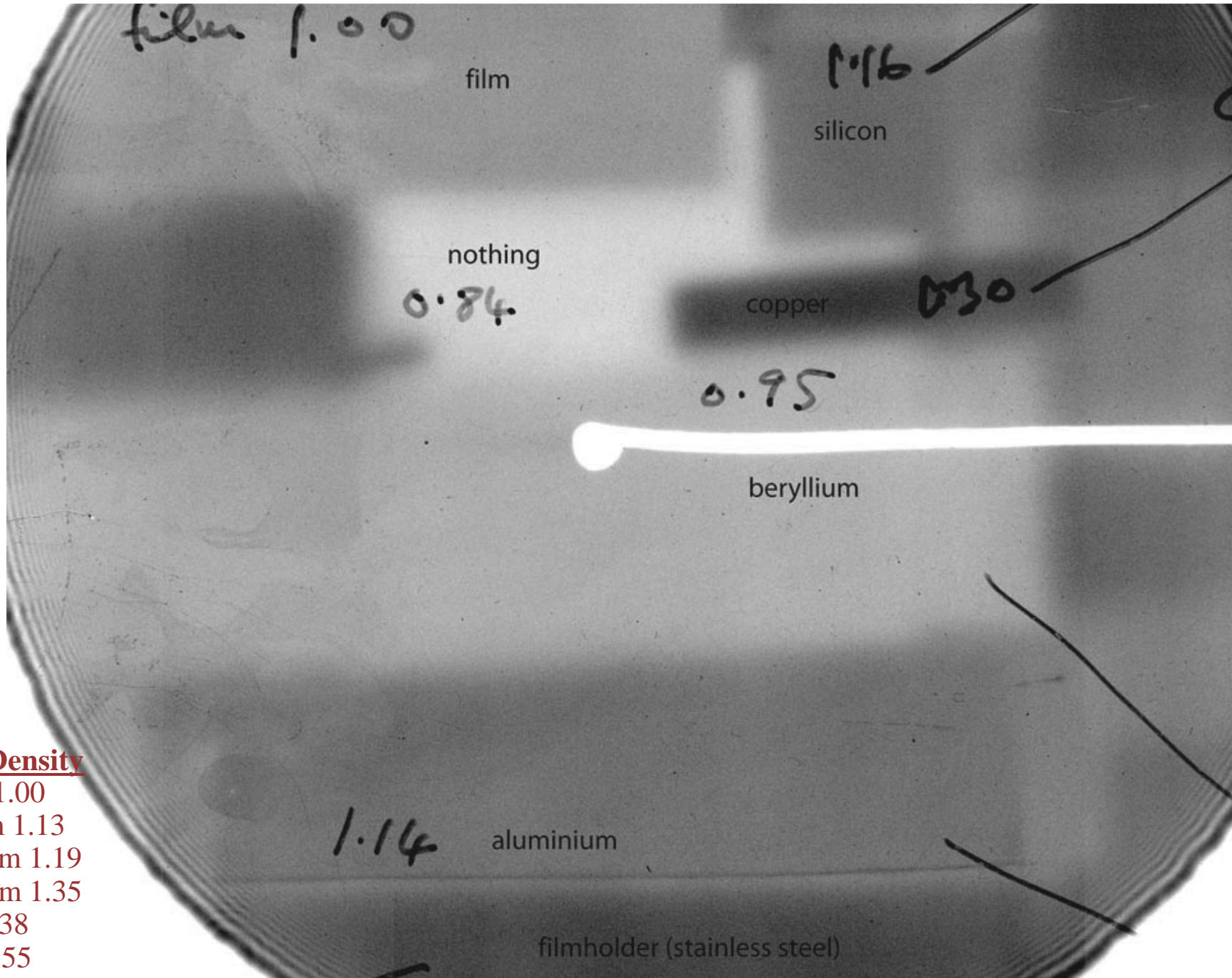
Detector thickness = 300 microns, pixel=55 microns

Extension of simulations to include energy deposition (GM)





Backscattering test – film loaded upside down above test materials



Optical Density

Vacuum 1.00

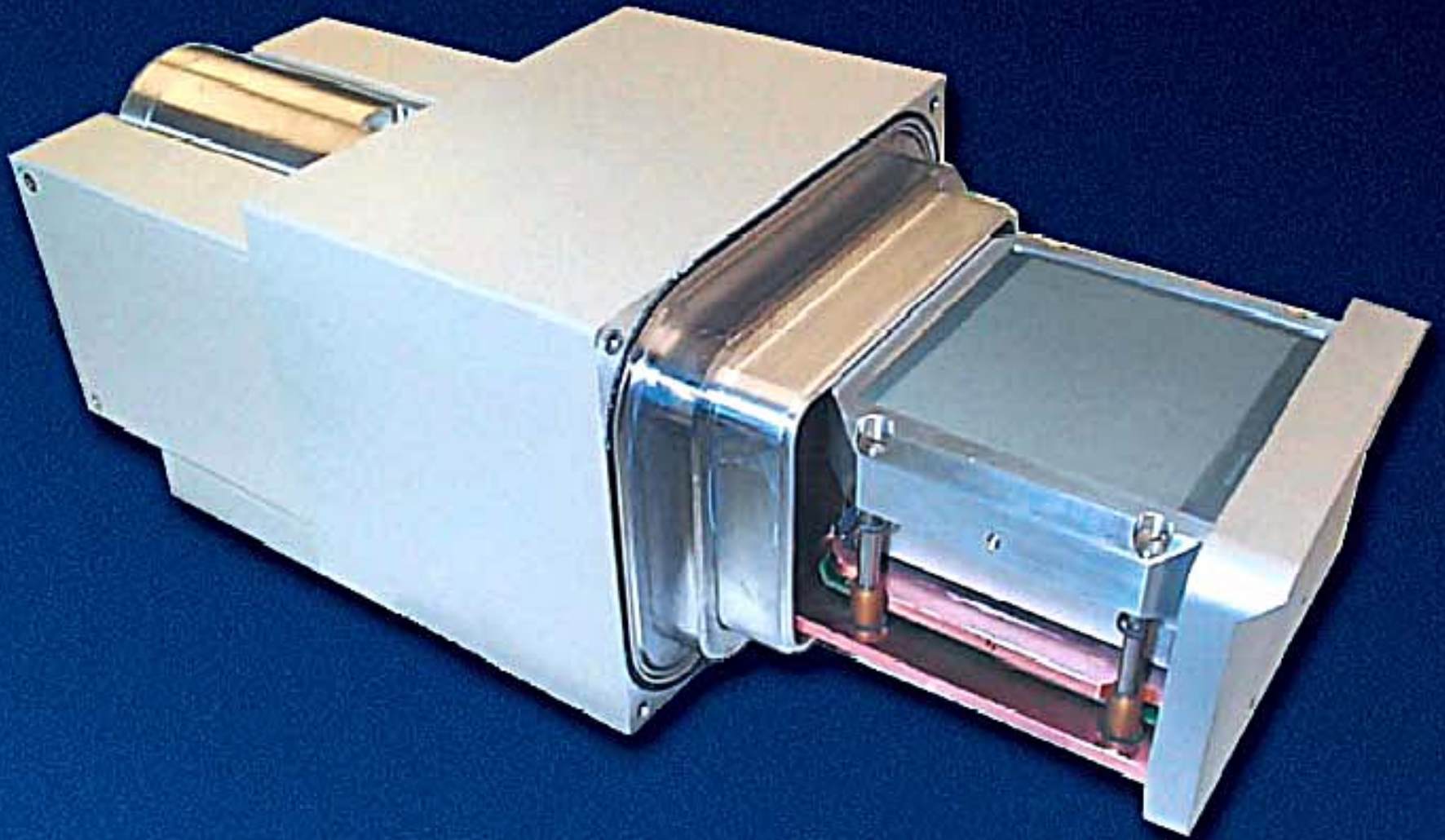
Beryllium 1.13

Plastic film 1.19

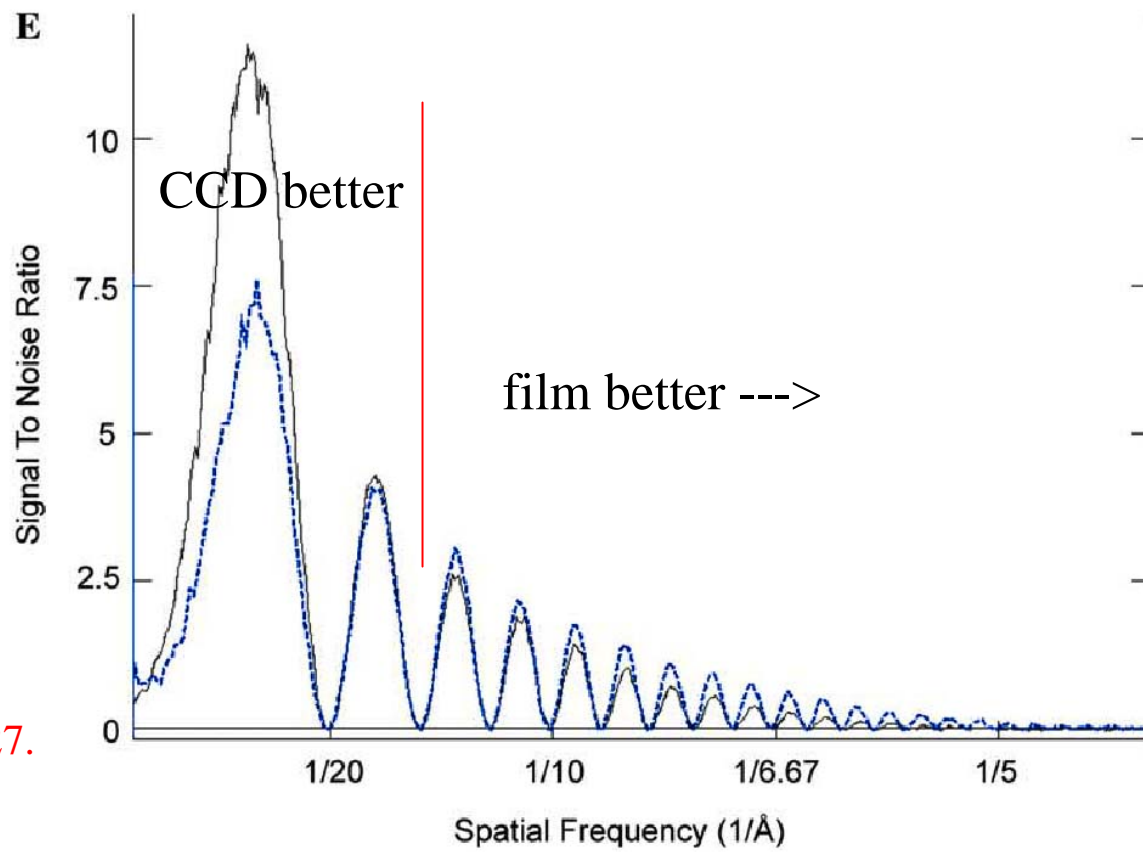
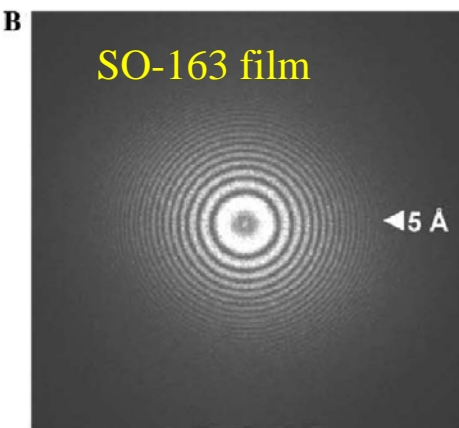
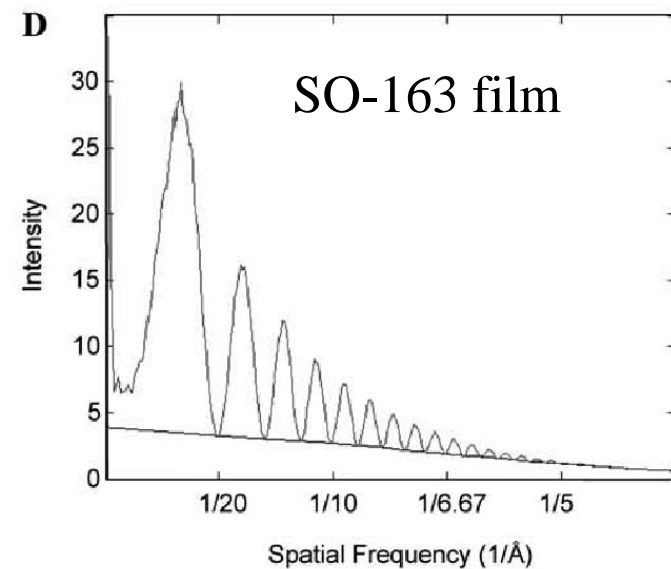
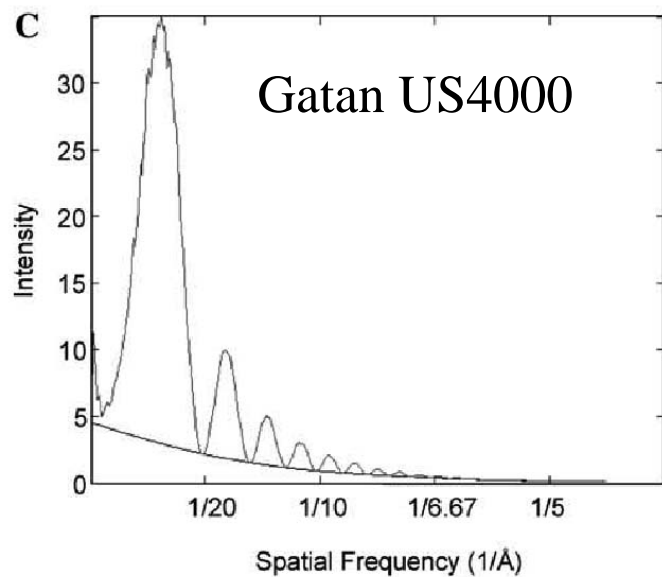
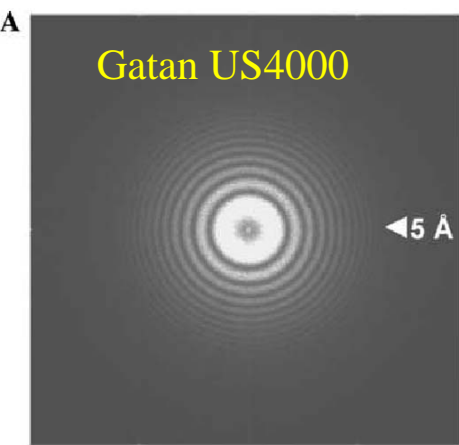
Aluminium 1.35

Silicon 1.38

Copper 1.55

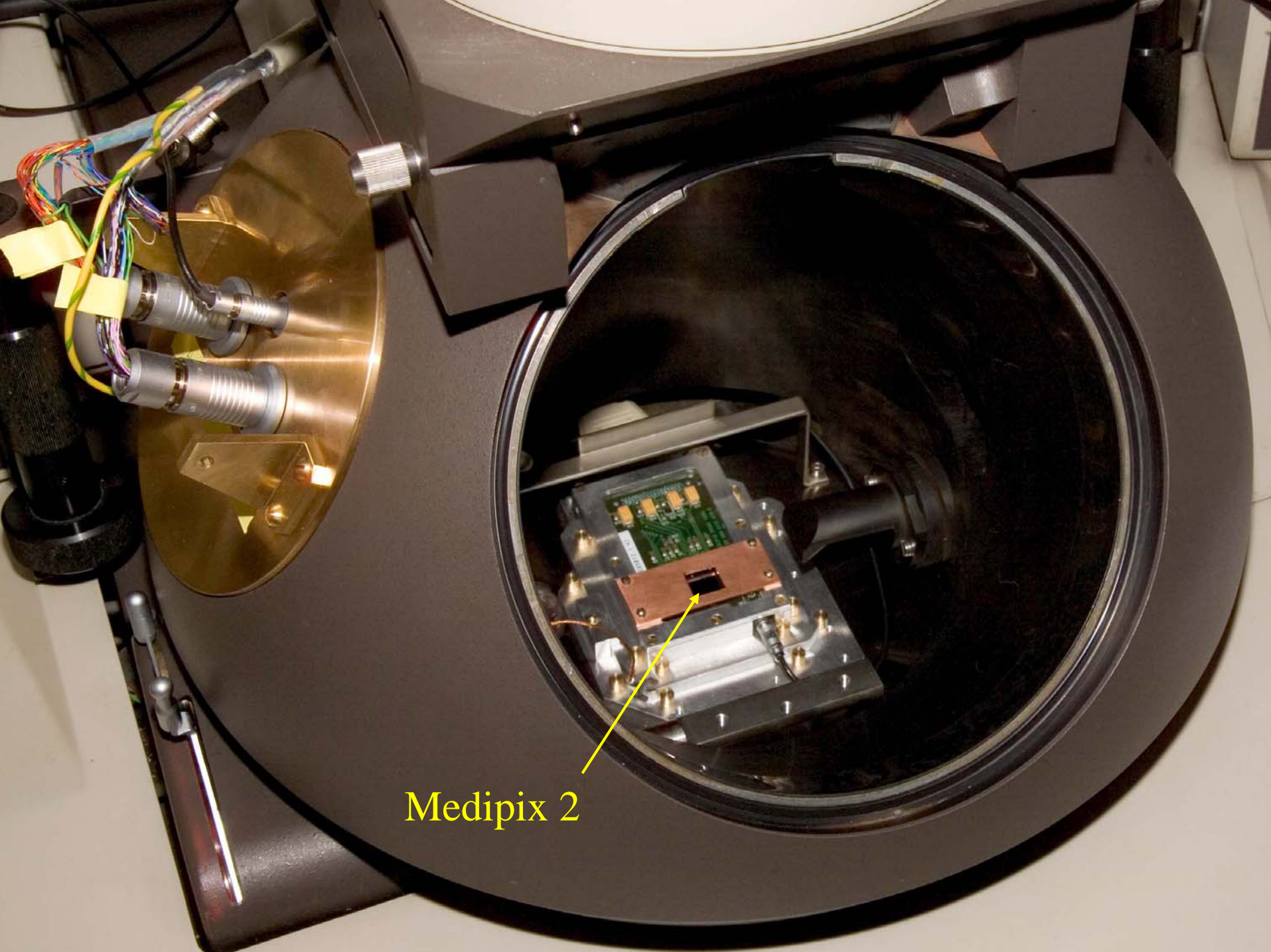


Gatan Ultrascan 4000

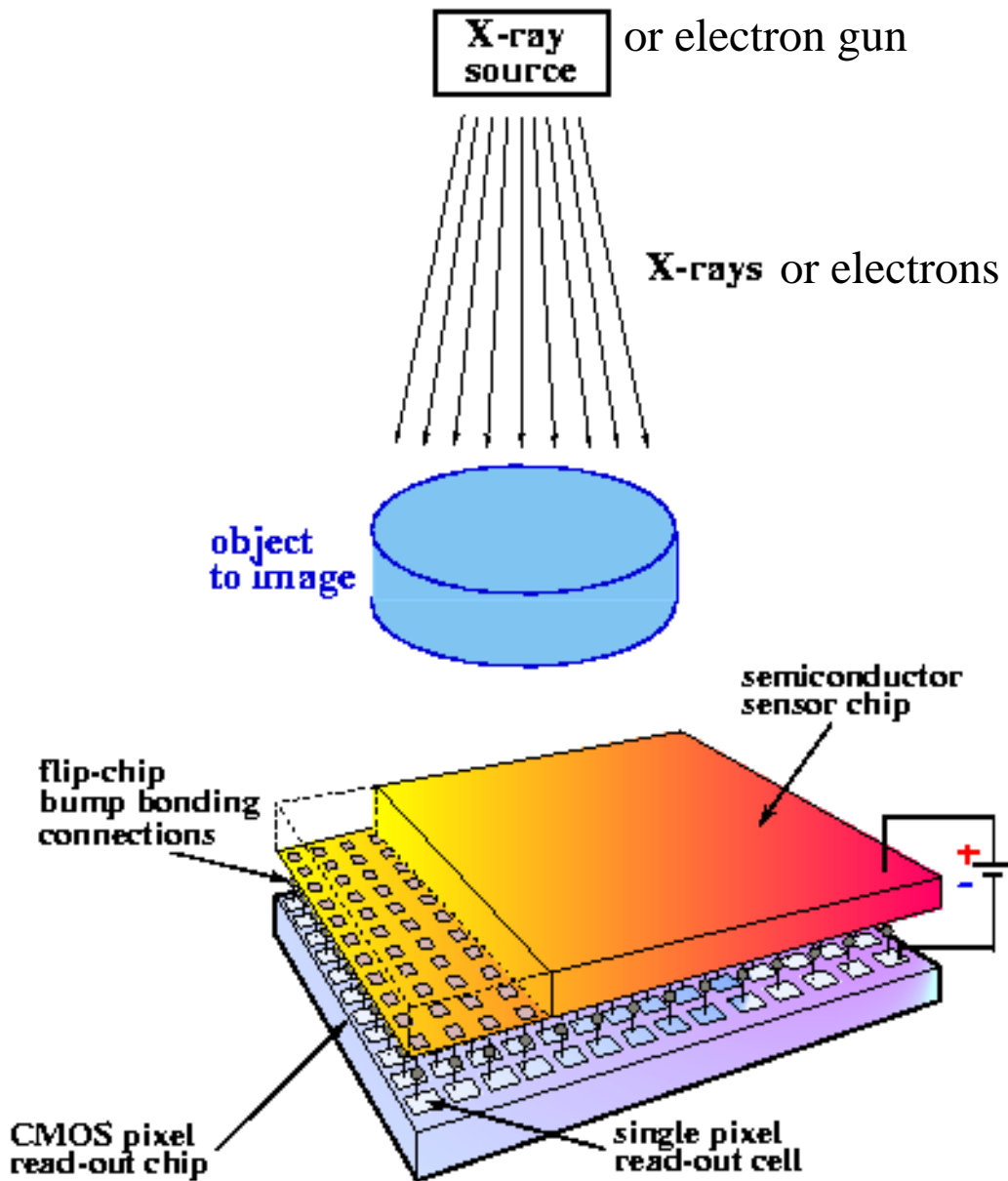


Gatan US4000 CCD camera
versus Kodak SO-163 film
for 200keV electrons

from
Booth et al (2004) JSB, **147**, 116-127.



Medipix 2

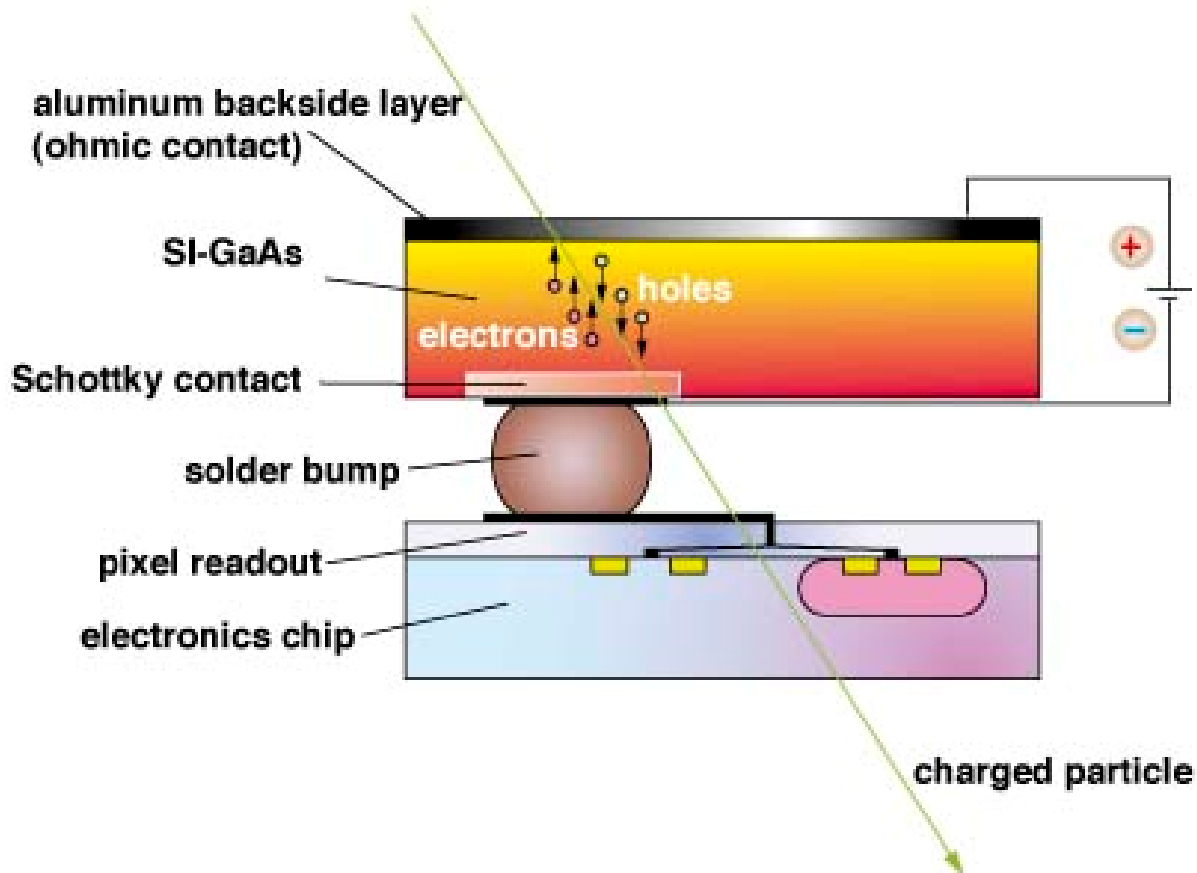


MediPix 2

hybrid pixel
sensor

Campbell et al
at CERN

Hybrid GaAs Pixel Detectors (Silicon/CdTe)



Medipix 2 - grid shadow

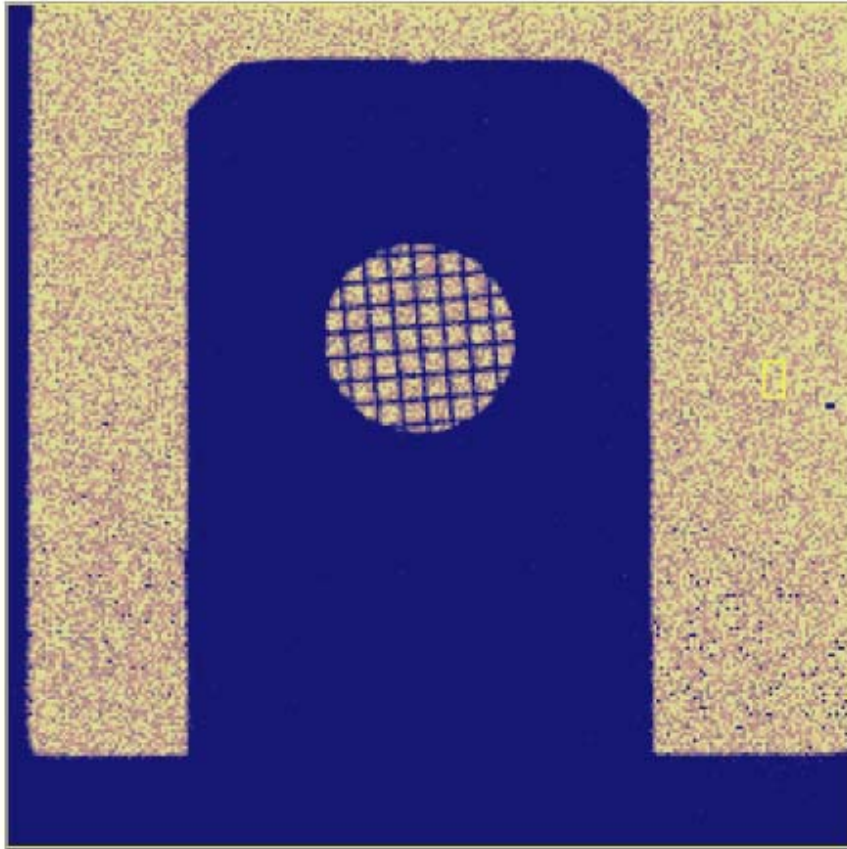


Image of grid with **18 electrons/pixel**

No counts are recorded in areas not exposed to incident electrons

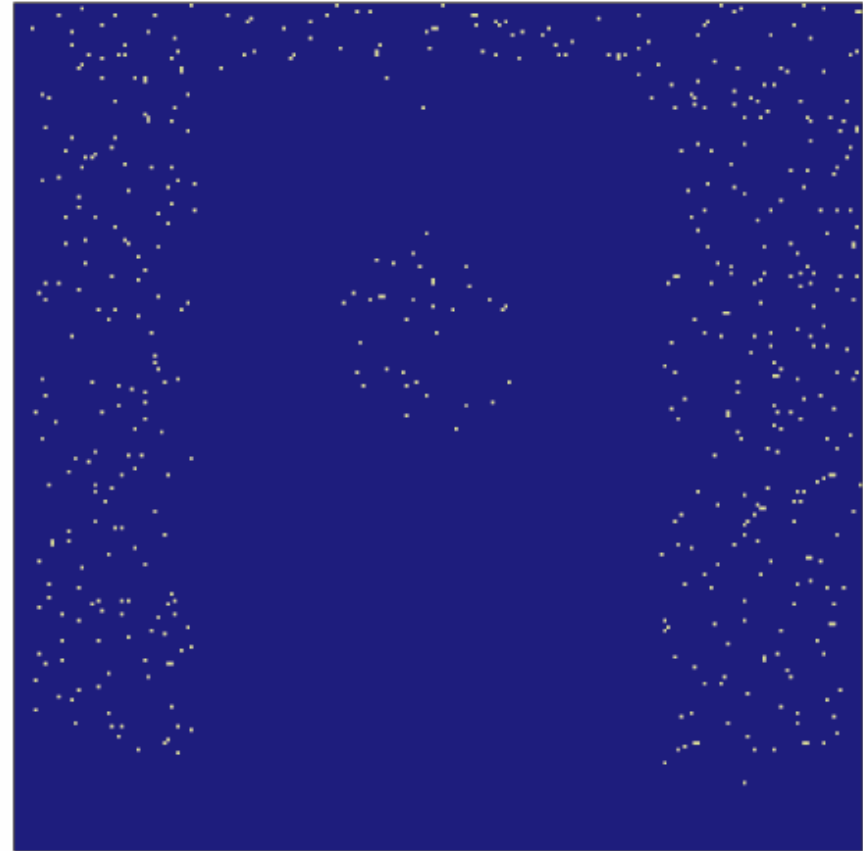
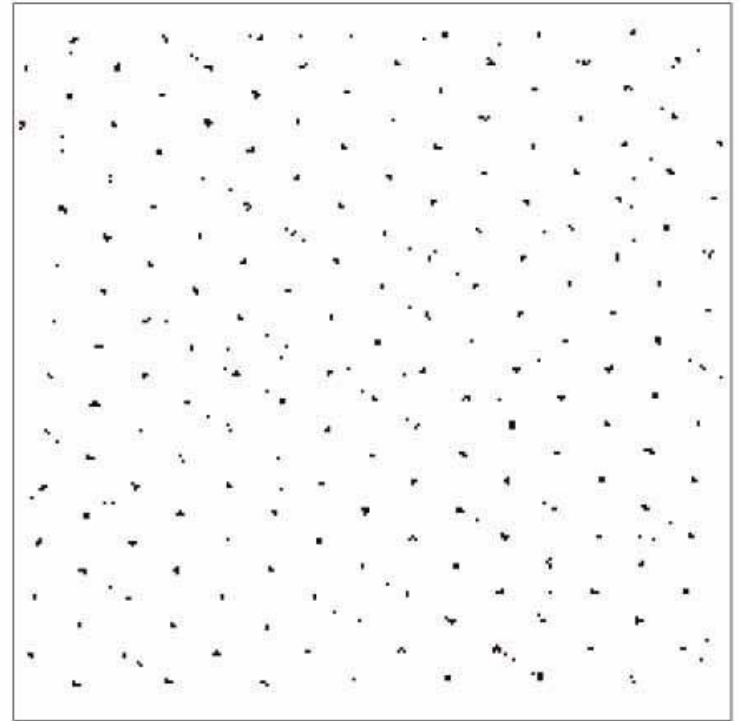
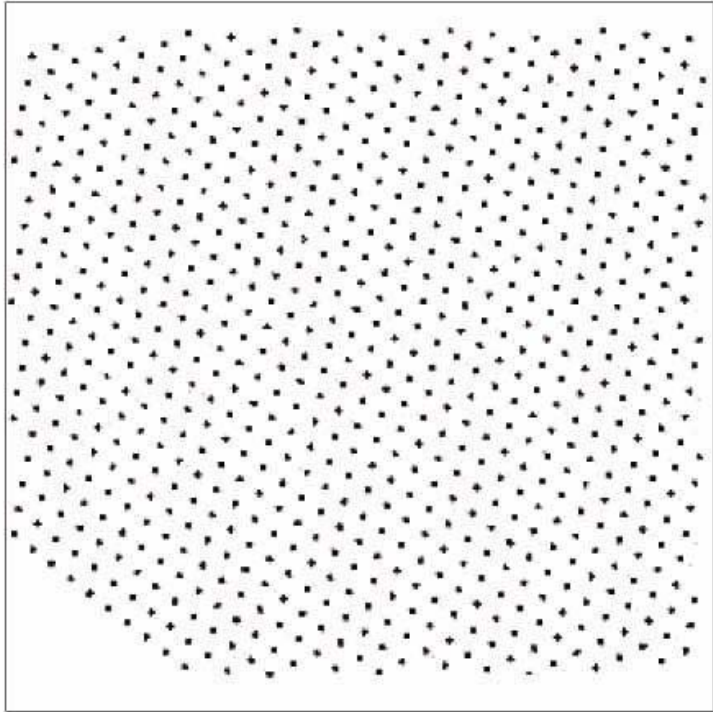


Image with **< 0.01 electron/pixel**

Electrons are almost all recorded in one pixel

Medipix 2 - raster of spots



Mean Intensity	111
Std Deviation	11

Mean Intensity	4.7
Std Deviation	1.8

Film exposure equivalent to above

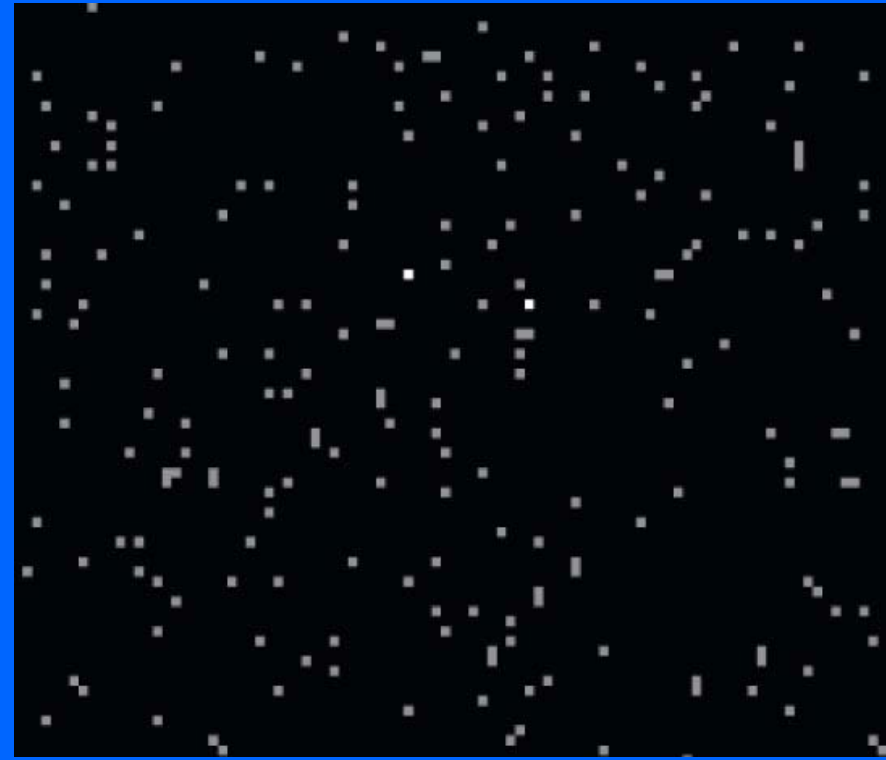
Mean Intensity	116
Std Deviation	24

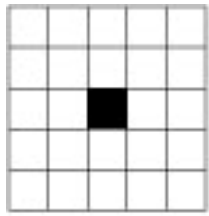
spots not visible, unmeasurable

120keV electrons/45keV threshold

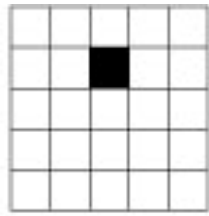


300keV electrons/80keV threshold

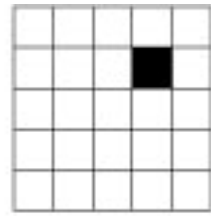




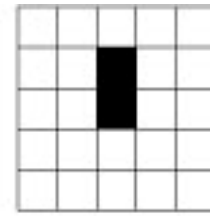
(a)



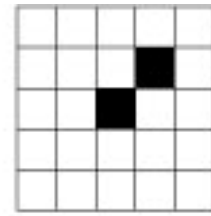
(b)



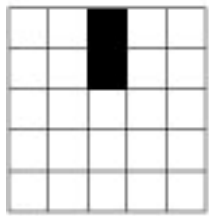
(c)



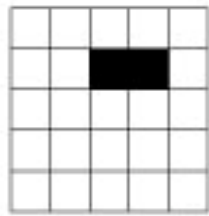
(d)



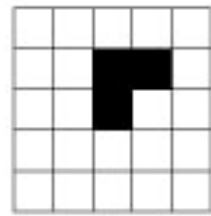
(e)



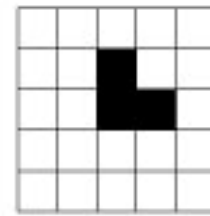
(f)



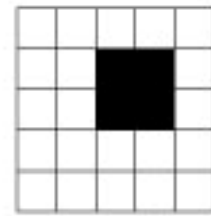
(g)



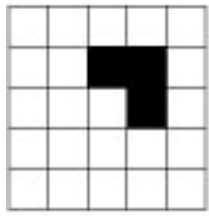
(h)



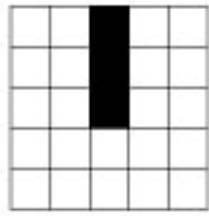
(i)



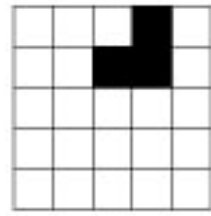
(j)



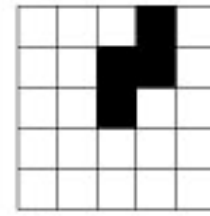
(k)



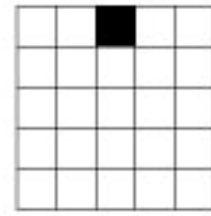
(l)



(m)



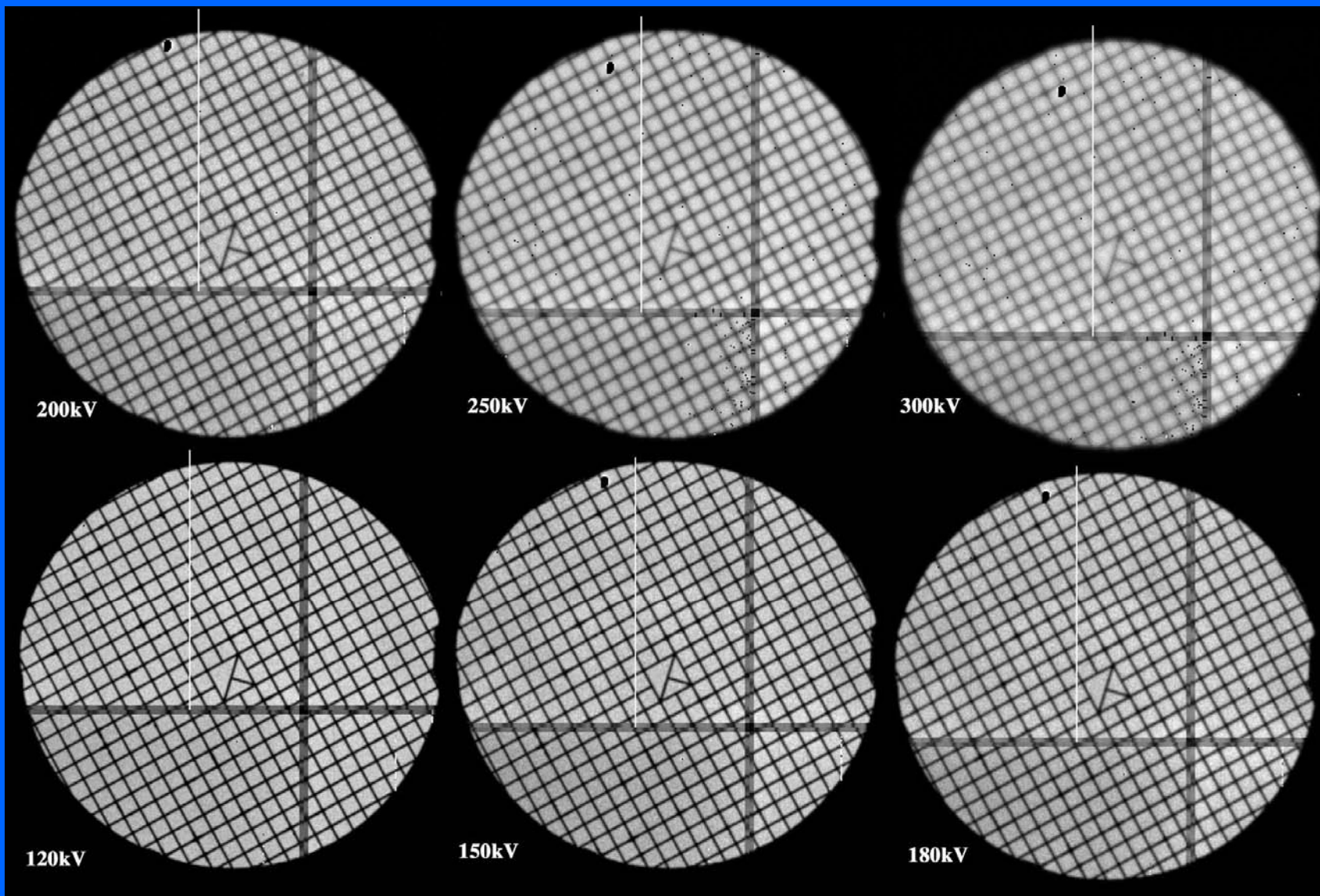
(n)



(o)

120keV electrons; a-c $\Delta E=80\text{keV}$, a-g 40keV, a-j 20keV, a-n $>0.5\%$, o - rare

Resolution of Quad_Medipix2 from 120 – 300 keV



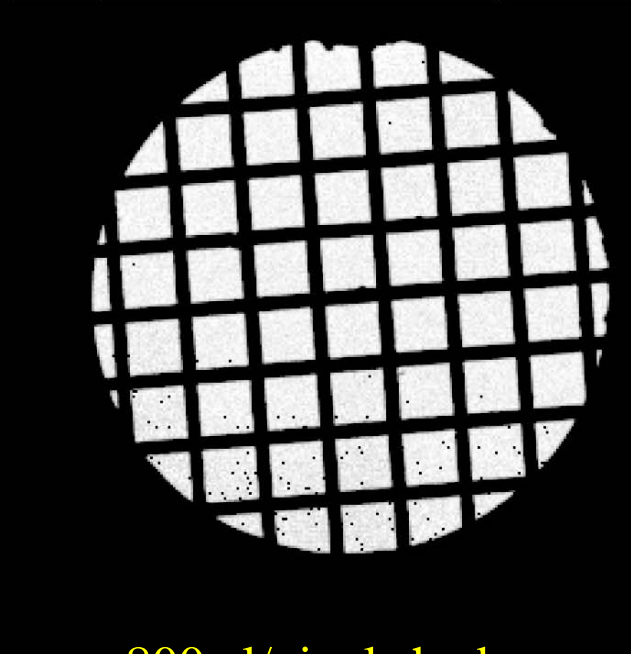
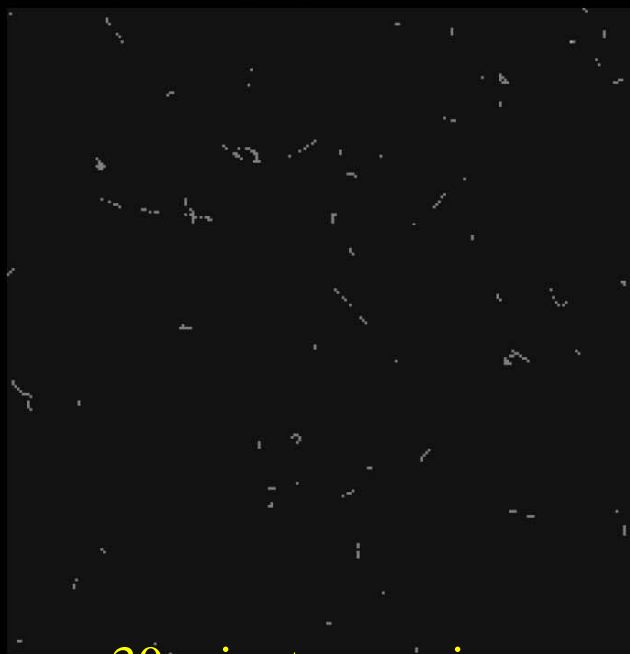
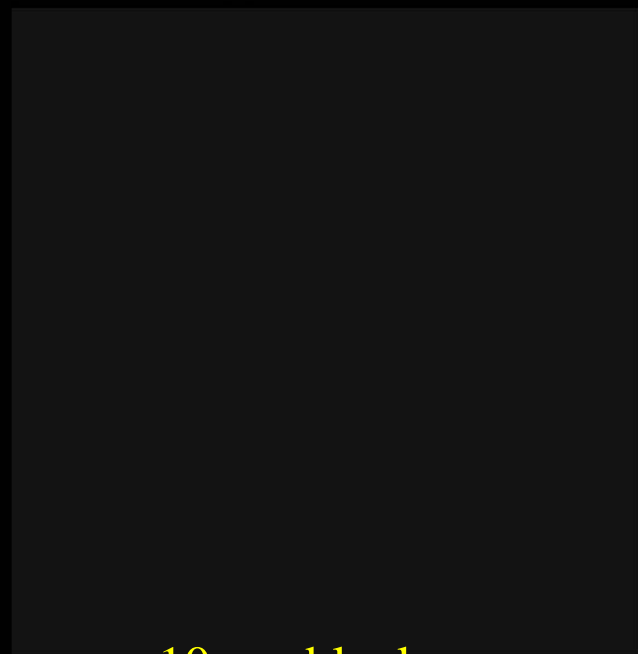
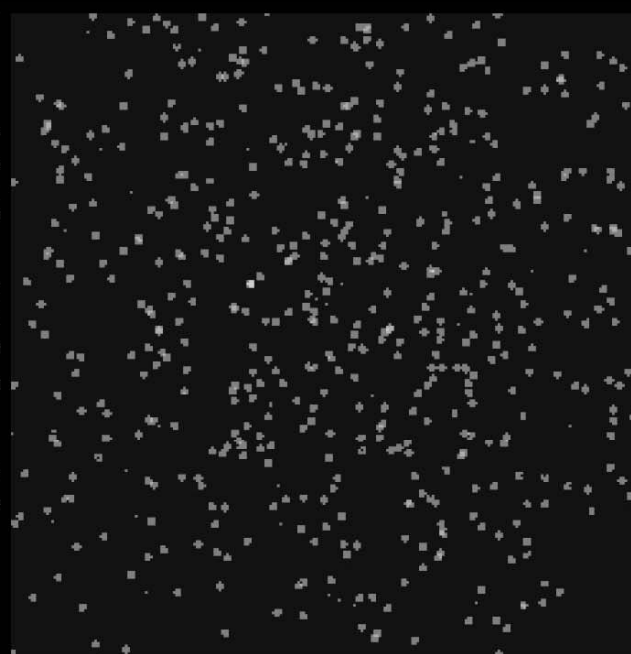
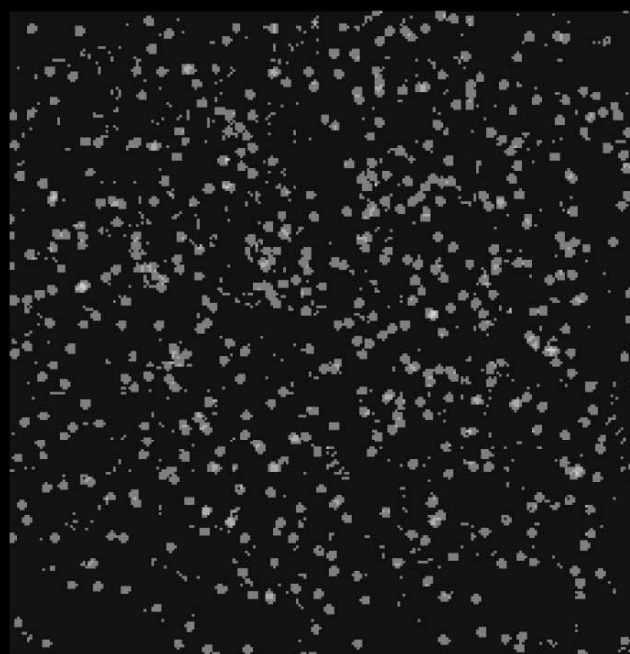
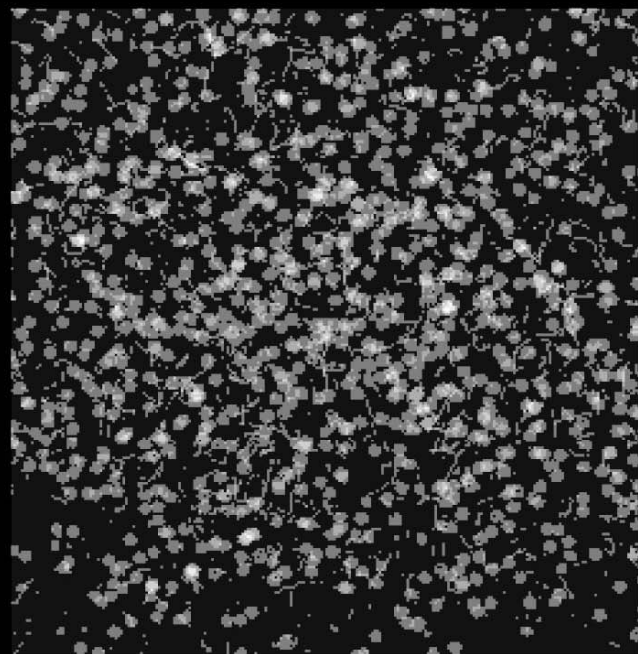
300 mesh grid, spacing ~650 microns in image

Cs137 β low

(scale 0-5)

Cs137 β med

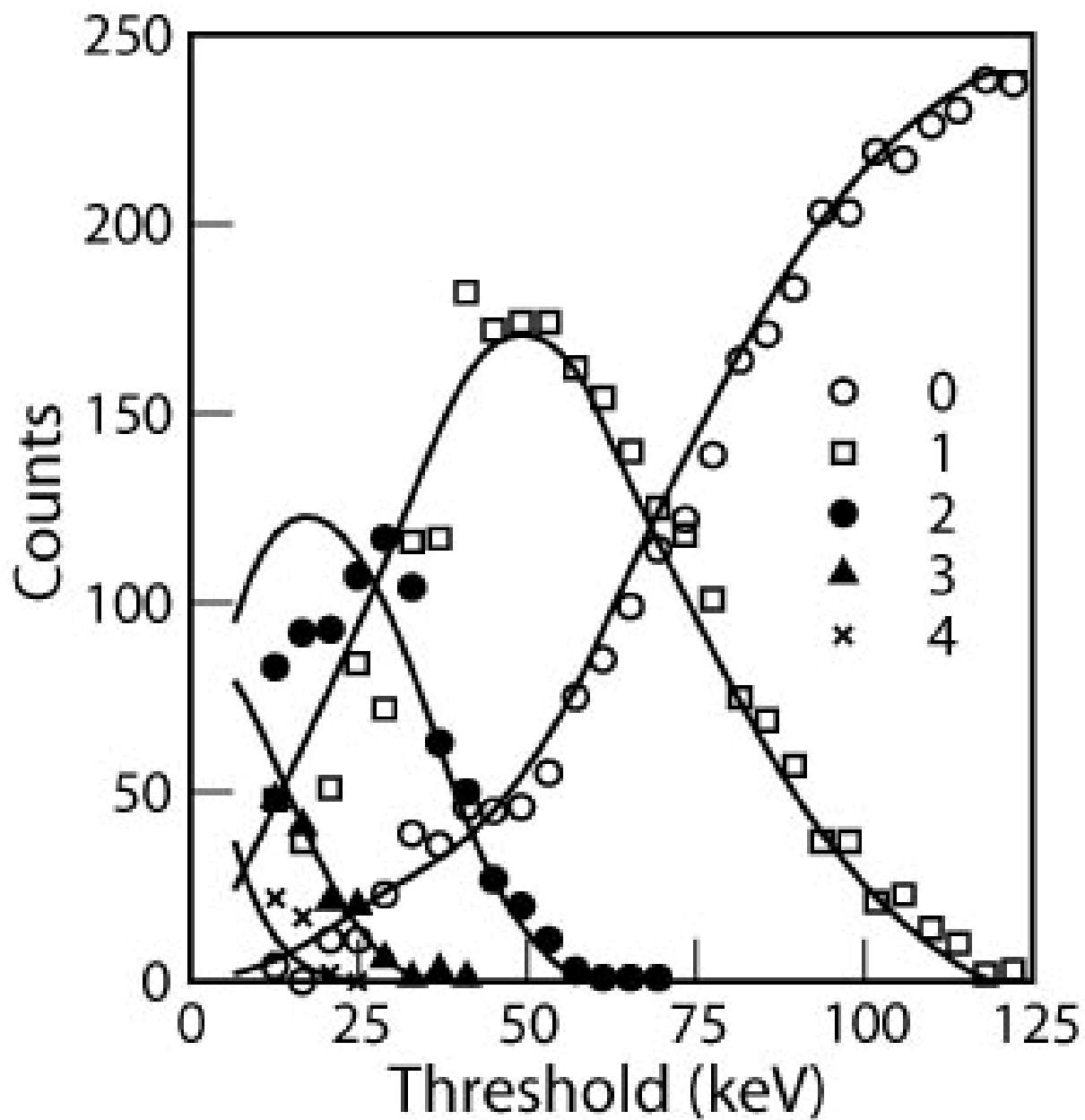
Cs137 β high



10 sec blank

30 minute cosmics

800 el/pixel shadow



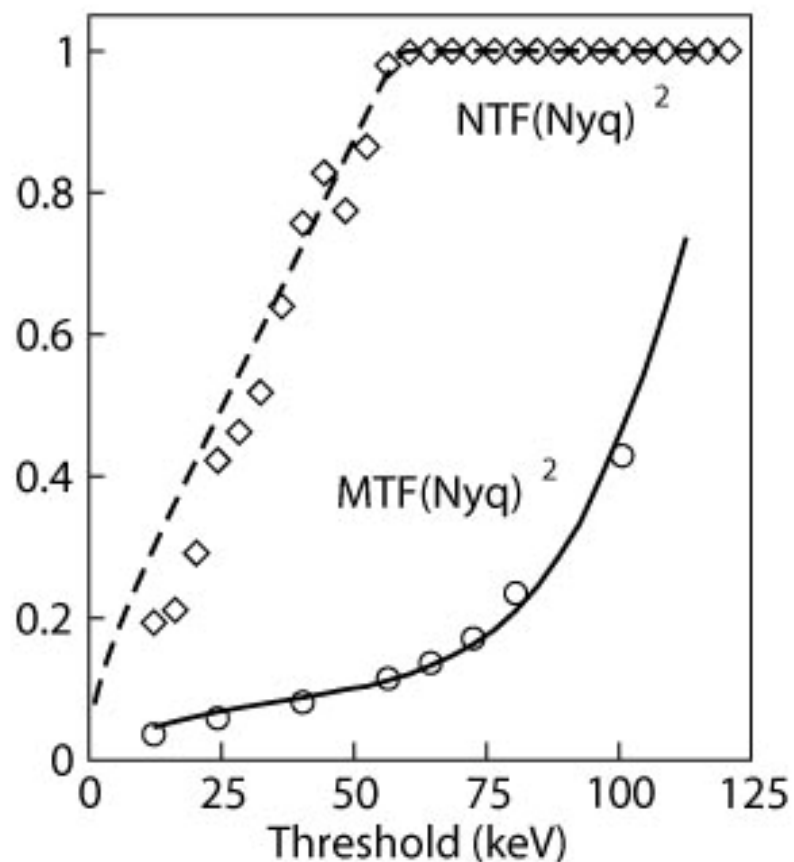
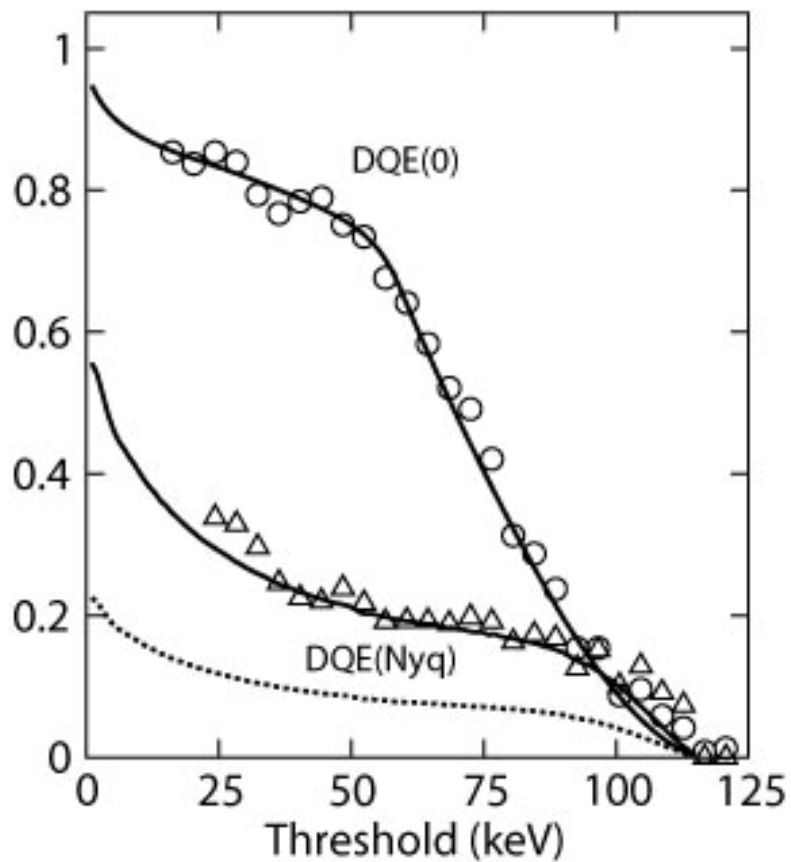
Some DQE formulae

$$\text{DQE}(0) = (\text{S}/\text{N}_{\text{out}})^2 / (\text{S}/\text{N}_{\text{in}})^2 \quad - \text{ any detector}$$

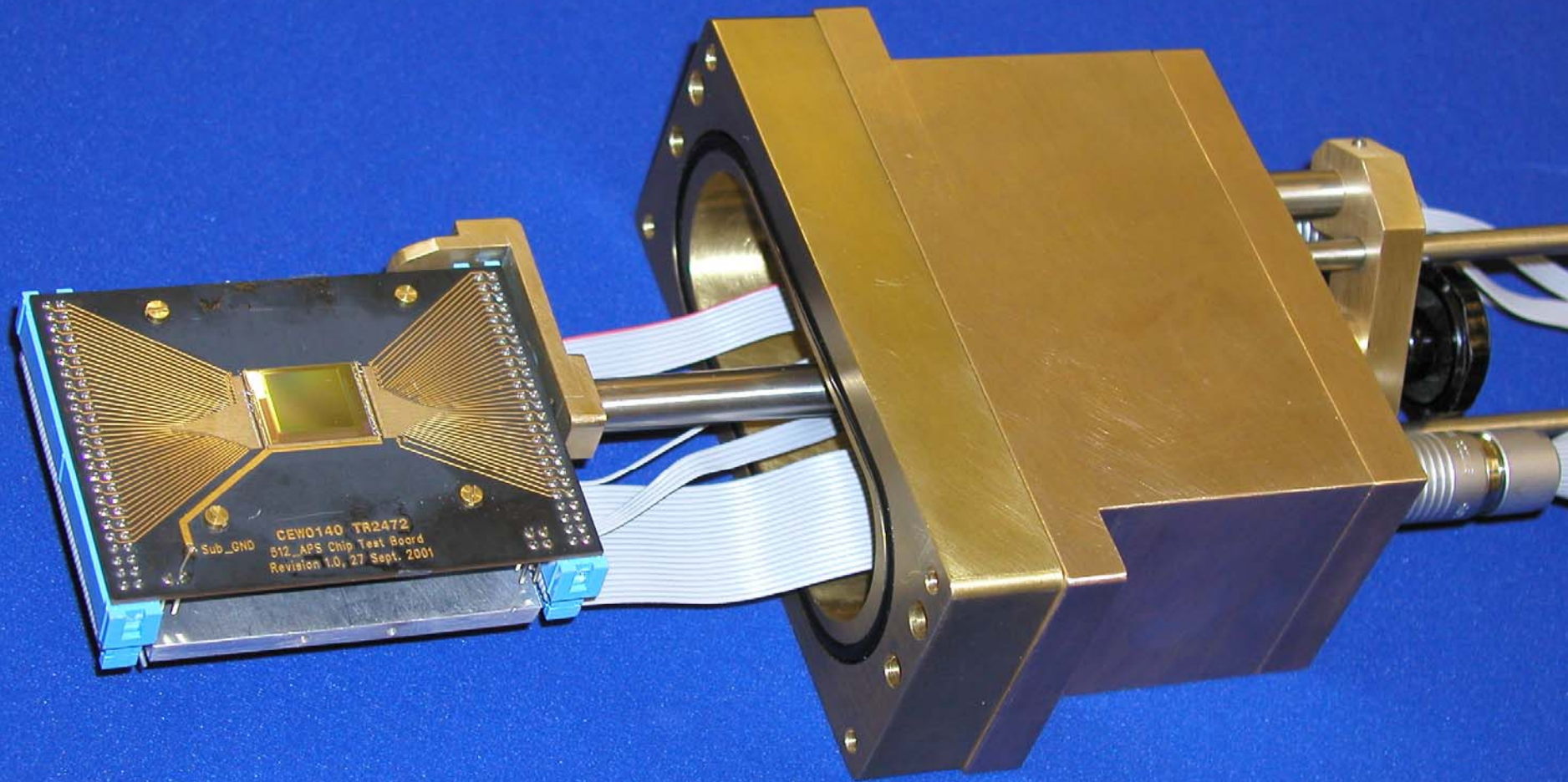
$$\text{DQE}(0) = (\sum i p_i)^2 / (\sum i^2 p_i) \quad - \text{ digital detector}$$

(where p_i is probability of recording a single incident electron in i pixels)

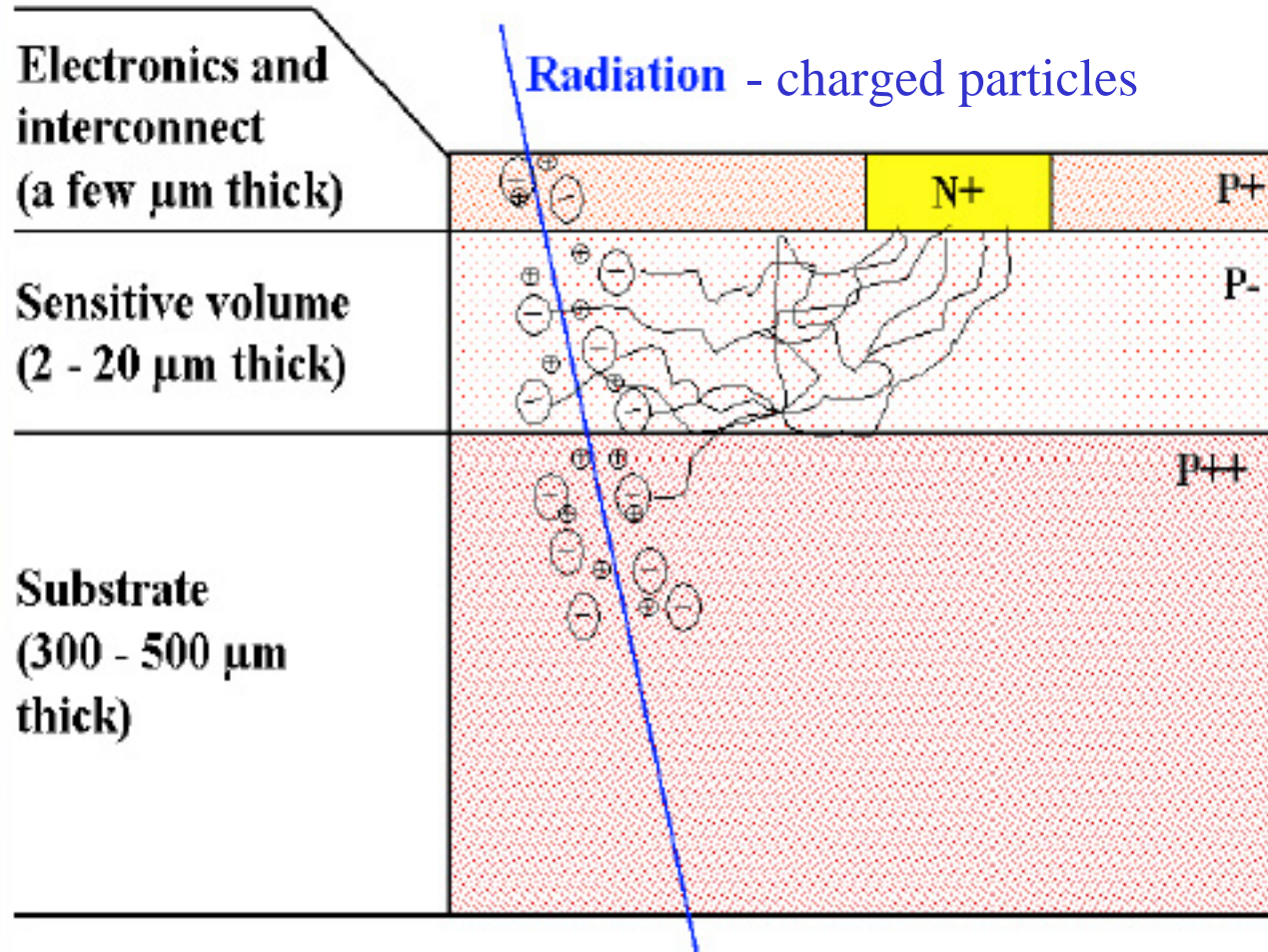
$$\text{DQE}(\omega) = \text{DQE}(0) \cdot \text{MTF}(\omega)^2 / \text{NTF}(\omega)^2$$



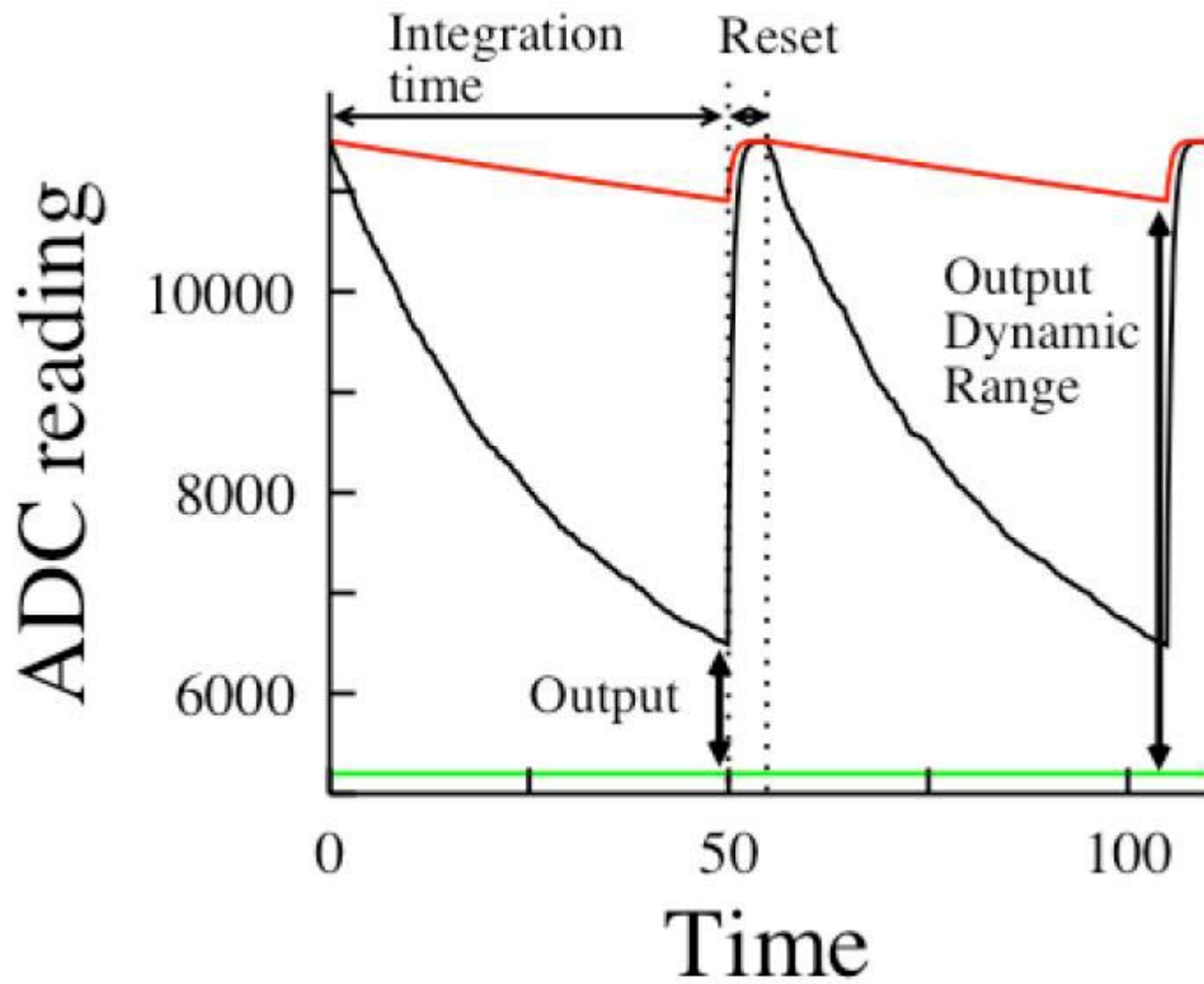
MAPS/CMOS in 35mm port on CM12



MAPS CMOS Detector



- no bias voltages
- charge diffusion
- 100% fill factor

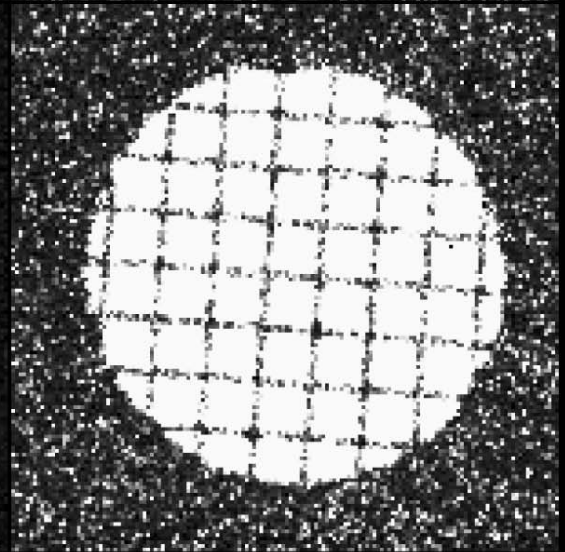
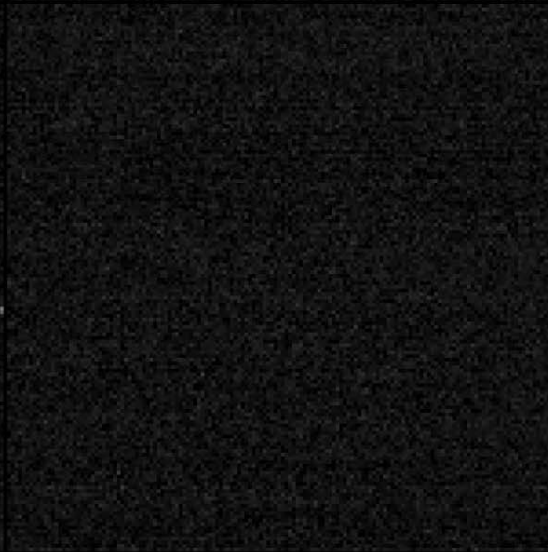
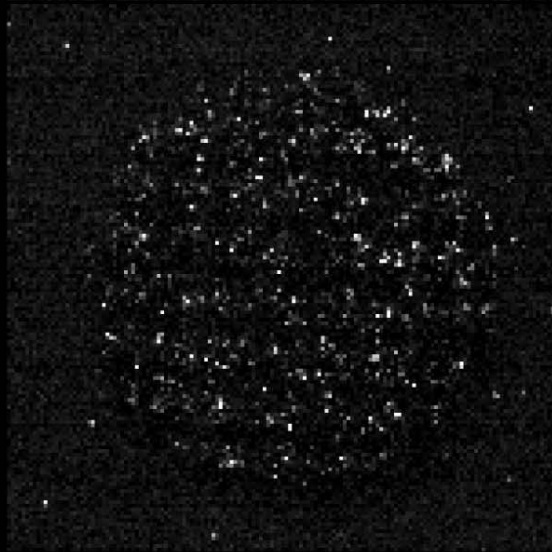
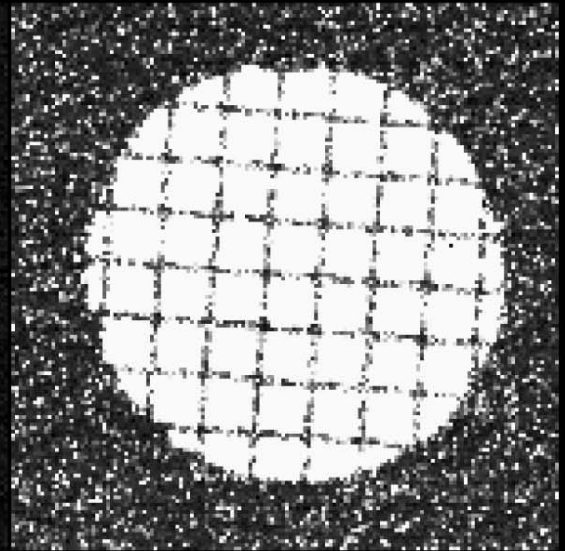
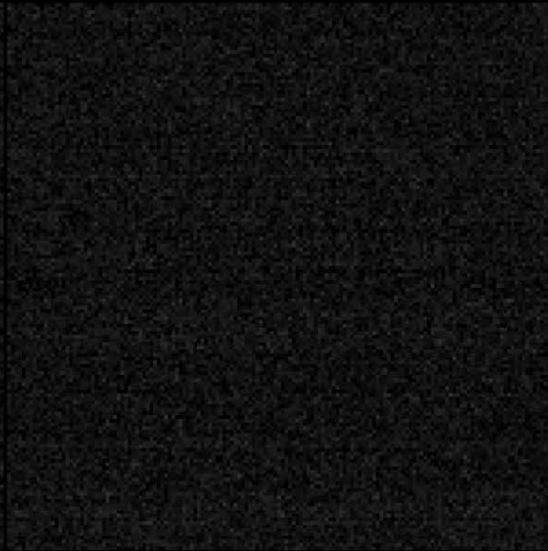
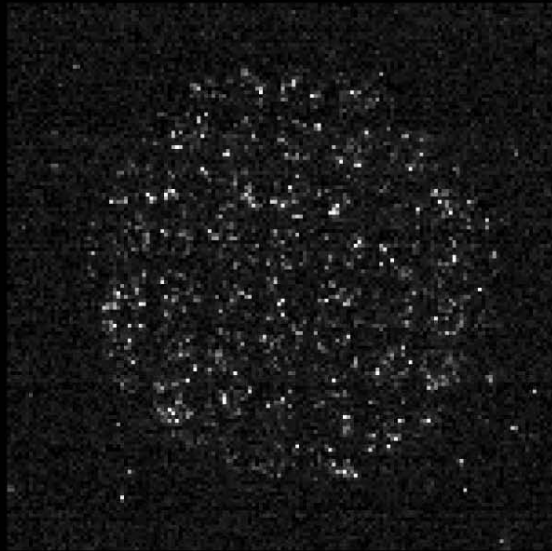


MAPS CMOS detector

6el/100pixels

blank

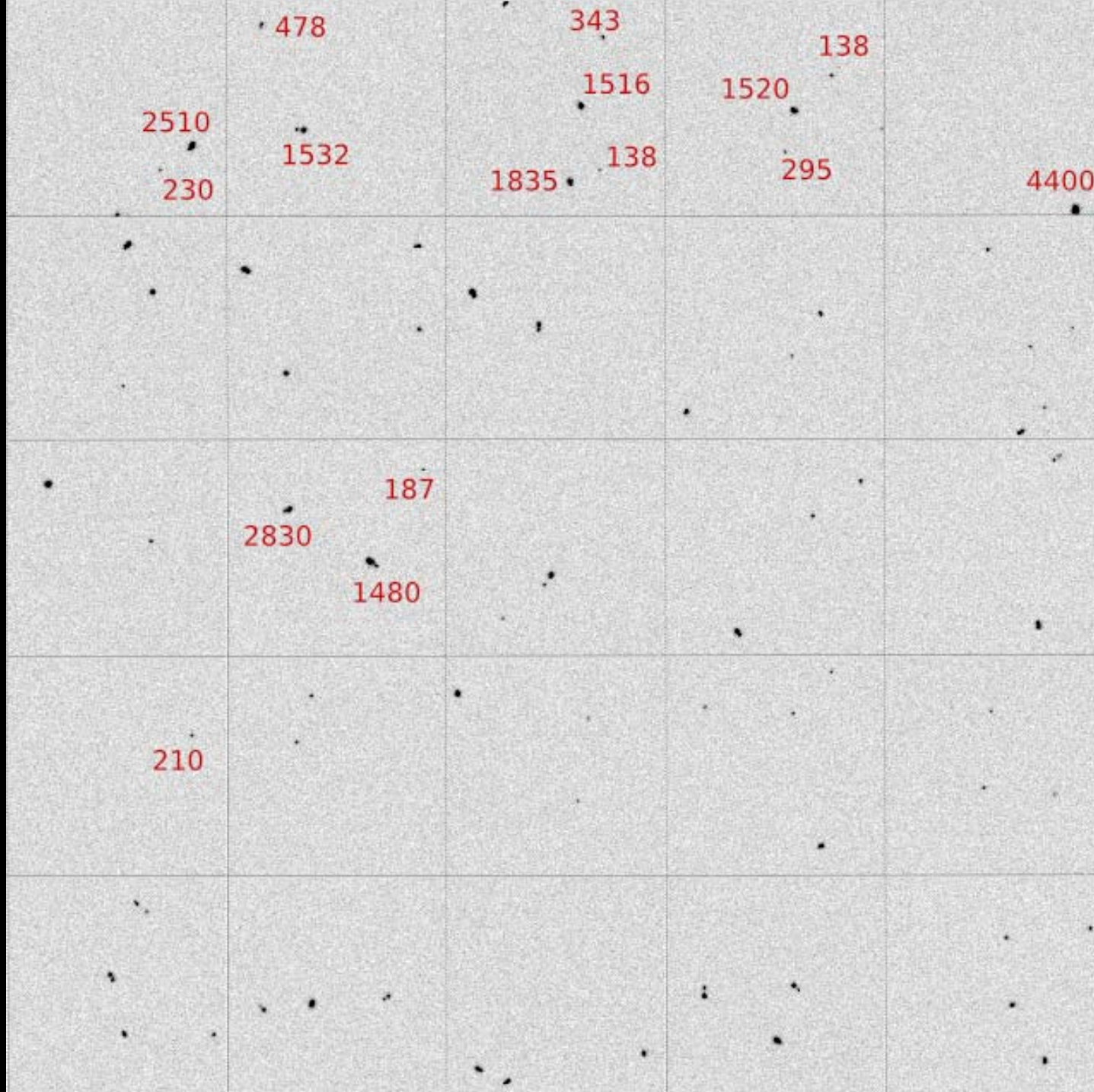
6el/pixel



6el/100pixels

blank

6el/pixel



MTF at Nyquist limit (% of maximum = $2/\pi$)

<u>Detector</u>	<u>Energy</u>	<u>Noise</u>	<u>MTF</u>	<u>pixel size</u>	<u># pixels on edge</u>
SO-163 film	120keV	~ 4	50%	7 μ m	12000
Gatan US4000	200keV	0.8	<10%	15 μ m	4000
Tietz 224	200keV	0.3	25%	24 μ m	2000
	300keV	0.5	24%	24 μ m	2000
Tietz 224 HD	120keV	0.06	25%	24 μ m	2000
Tietz 224 HD*	300keV	0.1	24%	24 μ m	2000
MAPS/CMOS	120keV	0.05	52%	25 μ m	525
HEPAPS-2	300keV	0.08	-	15 μ m	525
SIRA Star250	300keV	0.2	-	25 μ m	512
Medipix2	120keV	0.000001	50%	55 μ m	256

* = extrapolated

Detectors – Medipix & CMOS

Wasi Faruqi
Greg McMullan
David Cattermole